

DATA SHEET

SFT1402 — General-Purpose Switching Device Applications

Features

- Motor drive application.
- Low ON-resistance.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		35	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱D		11	А
Drain Current (PW≤10μs)	IDP	PW≤10µs, duty cycle≤1%	44	А
Allowable Power Dissipation	De		1.0	W
	PD	Tc=25°C	15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			L Locit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	35			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =35V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =5.5A	4.6	7.7		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=5.5A, VGS=10V		24	32	mΩ
	R _{DS} (on)2	ID=5.5A, VGS=4V		40	56	mΩ
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Marking : T1402

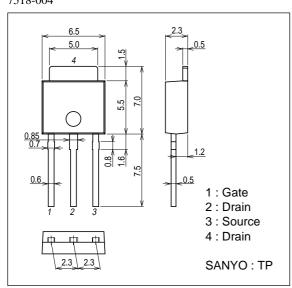
- Continued on next page.
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Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		1050		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		200		pF
Reverse Transfer Capacitance	Crss	VDS=20V, f=1MHz		140		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		14		ns
Rise Time	tr	See specified Test Circuit.		85		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		70		ns
Fall Time	tf	See specified Test Circuit.		60		ns
Total Gate Charge	Qg	V _{DS} =20V, V _{GS} =10V, I _D =11A		20		nC
Gate-to-Source Charge	Qgs	VDS=20V, VGS=10V, ID=11A		4.2		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =20V, V _{GS} =10V, I _D =11A		4.0		nC
Diode Forward Voltage	VSD	IS=11A, VGS=0V		0.93	1.2	V

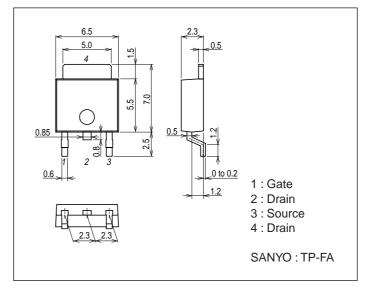
Package Dimensions

unit : mm (typ) 7518-004

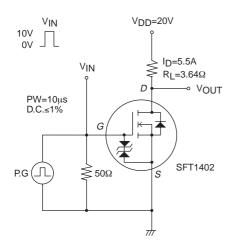


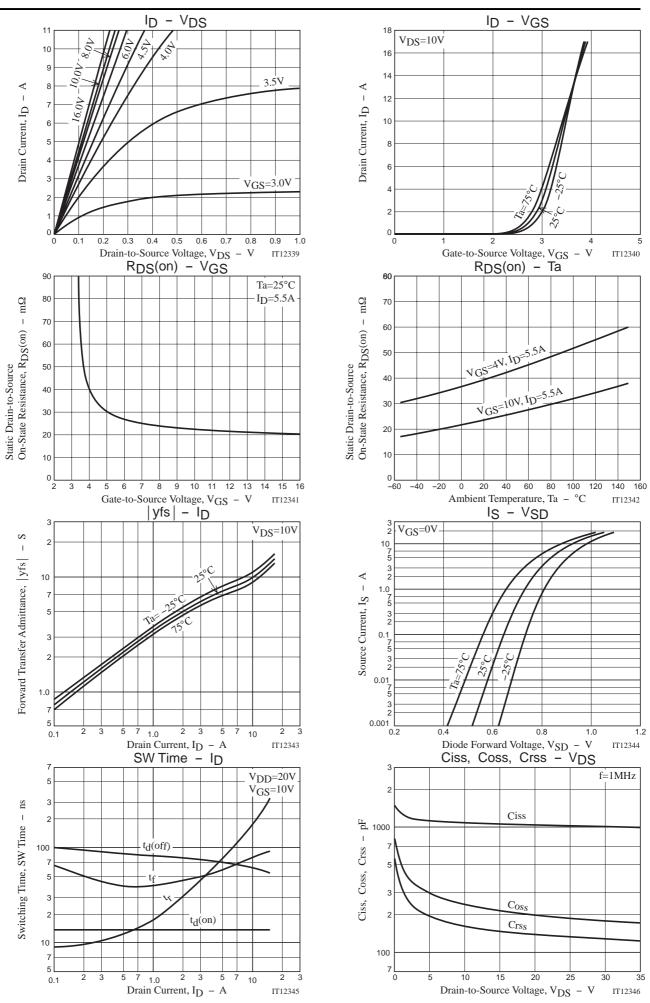
Package Dimensions

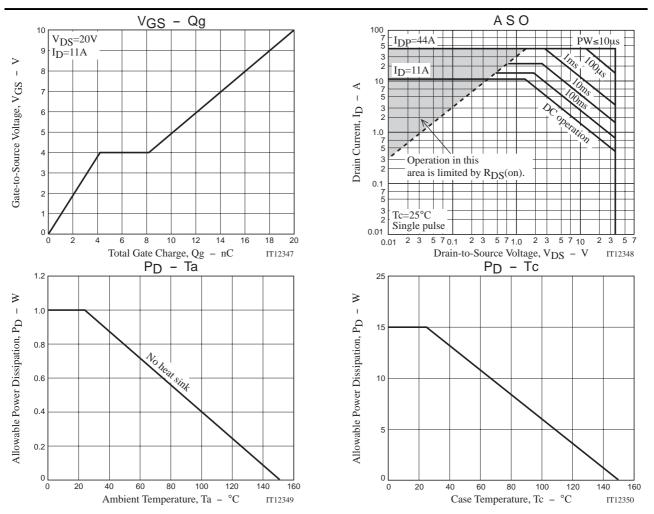
unit : mm(typ) 7003-004



Switching Time Test Circuit







Note on usage : Since the SFT1402 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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